Transistors Panasonic

## 2SA2164

### Silicon PNP epitaxial planar type

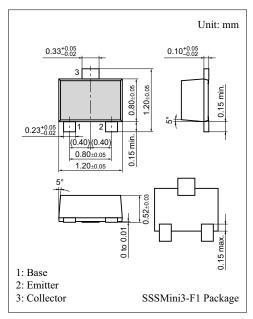
For high-frequency amplification

#### ■ Features

- High transfer ratio f<sub>T</sub>
- SSS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             | Symbol           | Rating      | Unit |  |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -30         | V    |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -20         | V    |  |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | -5          | V    |  |
| Collector current                     | $I_{C}$          | -30         | mA   |  |
| Collector power dissipation           | P <sub>C</sub>   | 100         | mW   |  |
| Junction temperature                  | T <sub>j</sub>   | 125         | °C   |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +125 | °C   |  |



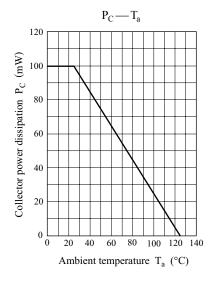
Marking Symbol: E

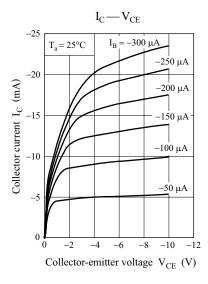
#### ■ Electrical Characteristics $T_a = 25$ °C±3°C

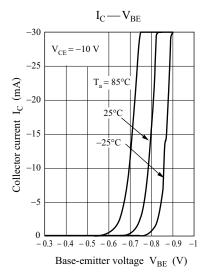
| Parameter                                     | Symbol               | Conditions   | Min | Тур  | Max  | Unit |
|---|----------------------|--|-----|------|------|------|
| Base-emitter voltage                          | $V_{BE}$             | $V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$                    |     | -0.7 |      | V    |
| Collector-base cutoff current (Emitter open)  | $I_{CBO}$            | $V_{\rm CB} = -10 \text{ V}, I_{\rm E} = 0$                        |     |      | -0.1 | μА   |
| Collector-emitter cut-off current (Base open) | I <sub>CEO</sub>     | $V_{CE} = -20 \text{ V}, I_{B} = 0$                                |     |      | -100 | μА   |
| Emitter-base cut-off current (Collector open) | $I_{EBO}$            | $V_{EB} = -5 \text{ V}, I_C = 0$                                   |     |      | -10  | μА   |
| Forward current transfer ratio                | h <sub>FE</sub>      | $V_{\rm CB} = -10 \text{ V}, I_{\rm E} = 1 \text{ mA}$             | 70  |      | 220  | _    |
| Collector-emitter saturation voltage          | V <sub>CE(sat)</sub> | $I_{\rm C} = -10  \text{mA}, I_{\rm B} = -1  \text{mA}$            |     | -0.1 |      | V    |
| Transition frequency                          | $f_T$                | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$  | 150 | 300  |      | MHz  |
| Noise figure                                  | NF                   | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 5 \text{ MHz}$    |     | 2.8  |      | dB   |
| Reverse transfer impedance                    | Z <sub>rb</sub>      | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 2 \text{ MHz}$    |     | 22   |      | Ω    |
| Common-emitter reverse transfer capacitance   | C <sub>re</sub>      | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 10.7 \text{ MHz}$ |     | 1.2  |      | pF   |

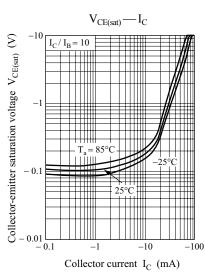
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

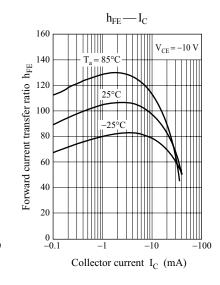
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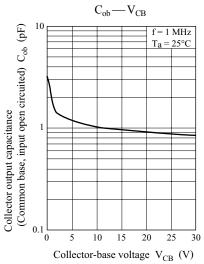








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